

VHF POWER MOSFET

N-Channel Enhancement Mode

DESCRIPTION:

The **VFT15-12** is Designed for General Purpose Class B Power Amplifier Applications up to 175 MHz.

FEATURES:

- $P_G = 12$ dB Typ. at 15 W /175MHz
- 20:1 Load VSWR Capability
- *Omnigold*TM Metalization System

MAXIMUM RATINGS

I_D	5.0 A
$V_{(BR)DSS}$	40 V
V_{DGR}	40 V
V_{GS}	± 20 V
P_{DISS}	95 W @ $T_C = 25^\circ C$
T_J	$-65^\circ C$ to $+200^\circ C$
T_{STG}	$-65^\circ C$ to $+150^\circ C$
q_{JC}	1.8 $^\circ C/W$

PACKAGE STYLE .380 4L FLG

DIM	MINIMUM inches / mm	MAXIMUM inches / mm
A	.220 / 5.59	.230 / 5.84
B	.785 / 19.94	
C	.720 / 18.29	.730 / 18.54
D	.970 / 24.64	.980 / 24.89
E		.385 / 9.78
F	.004 / 0.10	.006 / 0.15
G	.085 / 2.16	.105 / 2.67
H	.160 / 4.06	.180 / 4.57
I		.280 / 7.11
J	.240 / 6.10	.255 / 6.48

ORDER CODE: ASI10845

CHARACTERISTICS $T_C = 25^\circ C$

SYMBOL	TEST CONDITIONS		MINIMUM	TYPICAL	MAXIMUM	UNITS
$V_{(BR)DSS}$	$V_{GS} = 0$ V	$I_{DS} = 5$ mA	40	---	---	V
I_{DSS}	$V_{DS} = 15$ V	$V_{GS} = 0$ V	---	---	2.0	mA
I_{GSS}	$V_{DS} = 0$ V	$V_{GS} = 20$ V	---	---	1.0	mA
V_{GS}	$V_{DS} = 10$ V	$I_D = 25$ mA	1.0	---	6.0	V
G_{FS}	$V_{DS} = 10$ V	$I_D = 1.0$ A	500	---	---	mS
C_{iss}	$V_{DS} = 15$ V	$V_{GS} = 0$ V	F = 1.0 MHz	45		pF
C_{oss}				45		
C_{rss}				10		



P_G h_D	$V_{DD} = 12.5 \text{ V}$ W $F = 175 \text{ MHz}$	$I_{DQ} = 25 \text{ mA}$	$P_{OUT} = 15$	10 60	12 65		dB %
--	---	--------------------------	----------------	----------	----------	--	----------------